



30V P-Channel ENHANCEMENT MODE MOSFET

Voltage

30 V

Current

4 A

Features

- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-3A<87 $m\Omega$
- $R_{DS(ON)}$, V_{GS} @-10V, I_{D} @-4.1A<55 $m\Omega$
- Advanced Trench Process Technology
- High Density Cell Design For Ultra Low On-Resistance
- Specially Designed for DC/DC Converters
- Low Gate Charge
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std. (Halogen Free)

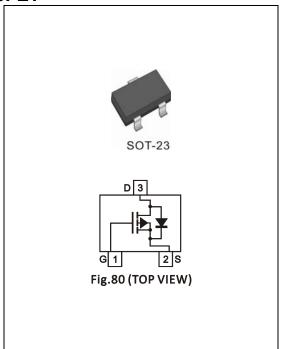
Mechanical Data

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Apporx. Weight: 0.0003 ounces, 0.0084 grams

• Marking:87



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|----------------------|-----------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | -30 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current | Ta=25°C | | -4 | А | |
| | Ta=70°C | l _D | -3.5 | | |
| Pulsed Drain Current (Note 1) | | I _{DM} | 20 | А | |
| Power Dissipation (Note 1) | T _a =25°C | 1 | 1.19 | W | |
| | T _a =70°C | P_{D} | 0.75 | | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55 to +150 | °C | |
| Thermal resistance - Junction to Ambient ^(Note 1) | | $R_{	hetaJA}$ | 125 | °C/W | |





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | | | | |
|----------------------------------|---------------------|---|------|-------|--------------|-------|--|--|--|--|
| Static | | | | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V,I _D =-250uA | -30 | - | - | V | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=-250uA$ | -1 | -1.55 | -3 | V | | | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-10V,I _D =-4.1A | - | 46 | 55 | mΩ | | | | |
| | | V _{GS} =-4.5V,I _D =-3A | - | 69 | 87 | | | | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-30V,V _{GS} =0V | - | - | -1 | uA | | | | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V,V _{DS} =0V | - | - | <u>+</u> 100 | nA | | | | |
| Diode Forward Voltage | V_{SD} | I _S =-1A,V _{GS} =0V | - | -0.81 | -1 | V | | | | |
| Dynamic | | | | | | | | | | |
| Total Gate Charge | Q_g | \/ - 45\/ - 4A | _ | 6.1 | - | nC | | | | |
| Gate-Source Charge | Q_{gs} | V _{DS} =-15V, I _D =-4A, | _ | 2 | - | | | | | |
| Gate-Drain Charge | Q_{gd} | V _{GS} =-4.5V | - | 2.3 | - | | | | | |
| Input Capacitance | Ciss | \(- 45\(\) \(-0\(\) | _ | 629 | - | pF | | | | |
| Output Capacitance | Coss | V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ | _ | 73 | - | | | | | |
| Reverse Transfer Capacitance | Crss | I=I.UIVIMZ | - | 61 | - | | | | | |
| Switching | | | | | | | | | | |
| Turn-On Delay Time | td _(on) | \(- 45\(\) \(- 40\(\) | _ | 55 | - | ns | | | | |
| Turn-Off Delay Time | td _(off) | V _{DS} =-15V, V _{GS} =-10V, | - | 22.5 | - | | | | | |
| Turn-On Rise Time | t _r | $R_G=3.3\Omega,R_G=3.9\Omega,$ | - | 33.9 | - | | | | | |
| Turn-Off Fall Time | t _f | | - | 9.8 | - | | | | | |

NOTES:

^{1.} Mounted on 1 in² FR-4 PCB.





TYPICAL CHARACTERISTIC CURVES

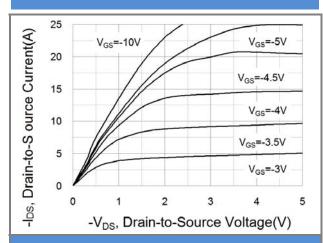


Fig.1 Output Characteristics

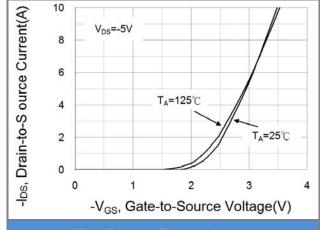


Fig.2 Transfer Characteristics

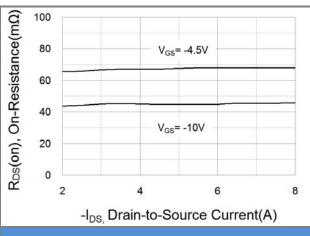


Fig.3 On-Resistance vs. Drain Current

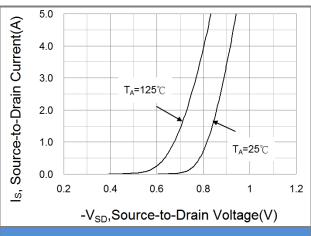


Fig.4 Source-Drain Diode Forward Voltage

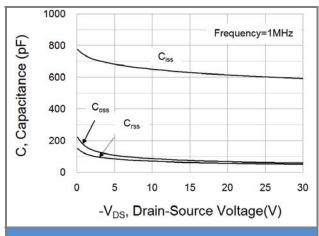


Fig.5 Capacitance vs. Drain-Source Voltage

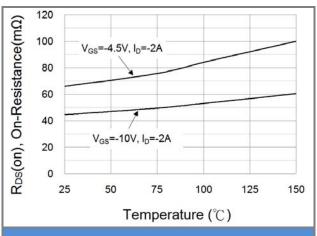


Fig.6 On-Resistance vs. Junction temperature

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TYPICAL CHARACTERISTIC CURVES

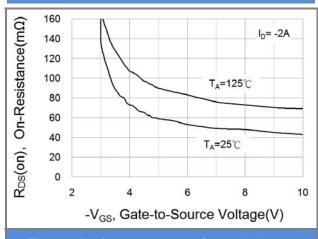
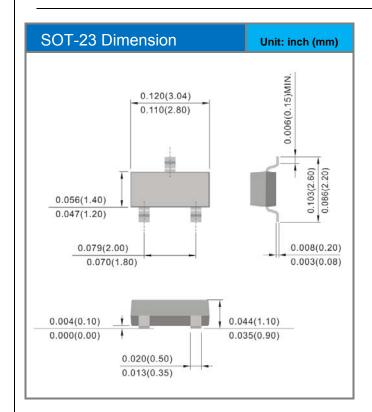


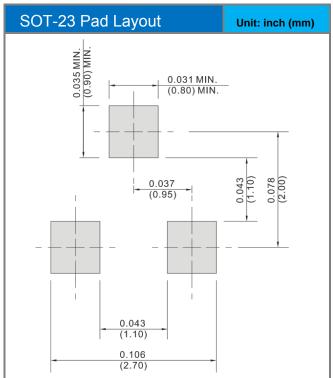
Fig.7 On-Resistance vs. Gate-Source Voltage



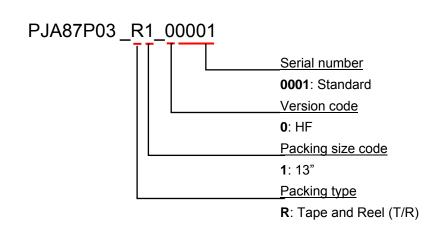


MECHANICAL DATA





ORDER INFORMATION



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